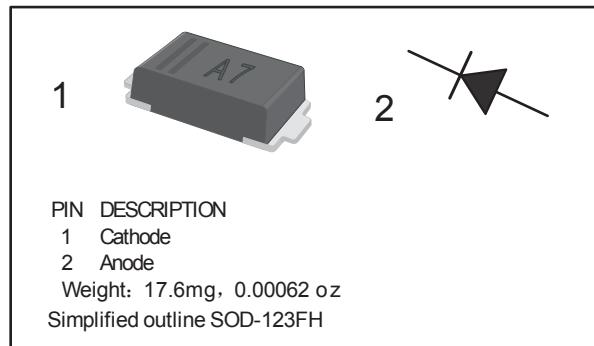


Rectifier Diodes

S1AFH~S1MFH

■ Features

- Surface Mount General Purpose Silicon Rectifiers
- Reverse Voltage - 50 to 1000 V
- Forward Current: 1 A



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	S1AFH	S1BFH	S1DFH	S1GFH	S1JFH	S1KFH	S1MFH	Unit
Repetitive Peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Surge Peak reverse voltage	V _{RSM}	35	70	140	280	420	560	700	
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	
Forward voltage @I _F =1A	V _F				1.1				
Averaged forward current. @ Ta=65°C	I _{FAV}				1				A
Peak forward surge current	I _{FSM}				25				
Maximum DC Reverse Current Ta=25°C Ta=125°C	I _R				5				μA
					100				
Typical Junction Capacitance *1	C _j				4				pF
Thermal Resistance Junction to Ambient*2	R _{θ JA}				180				°C/W
Junction temperature	T _j				150				°C
Storage temperature	T _{tsg}				-55 to 150				

* 1 Measured at 1 MHz and applied reverse voltage of 4 V D.C

* 2 Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

■ Marking

NO.	S1AFH	S1BFH	S1DFH	S1GFH	S1JFH	S1KFH	S1MFH
Marking	A1	A2	A3	A4	A5	A6	A7

Rectifier Diodes

S1AFH~S1MFH

■ Typical Characteristics

Fig.1 Forward Current Derating Curve

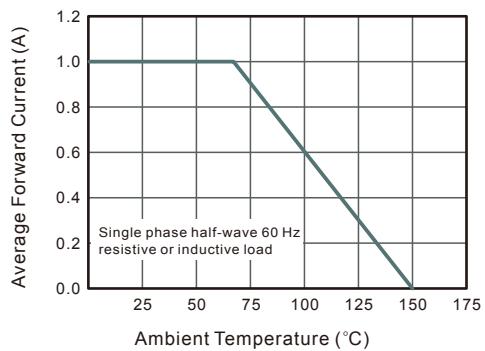


Fig.2 Typical Instantaneous Reverse Characteristics

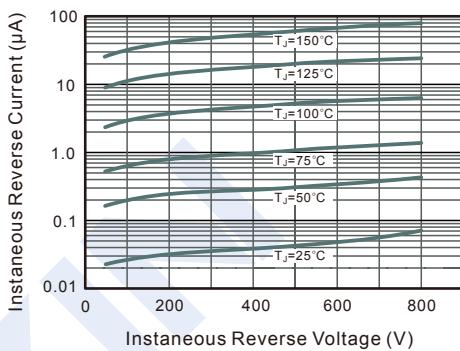


Fig.3 Typical Forward Characteristic

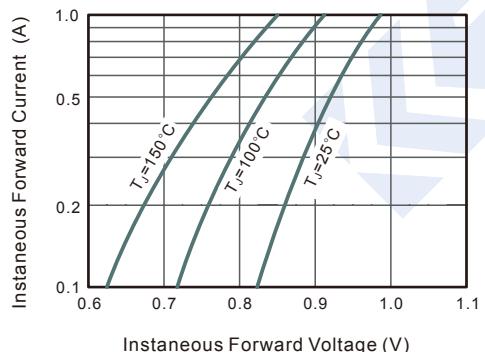
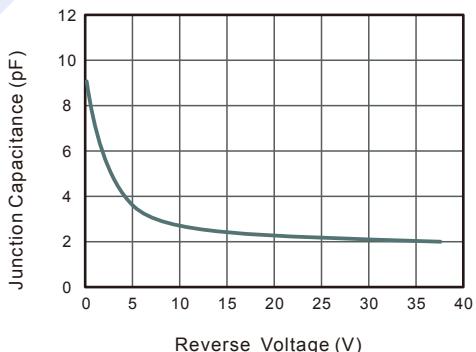


Fig.4 Typical Junction Capacitance

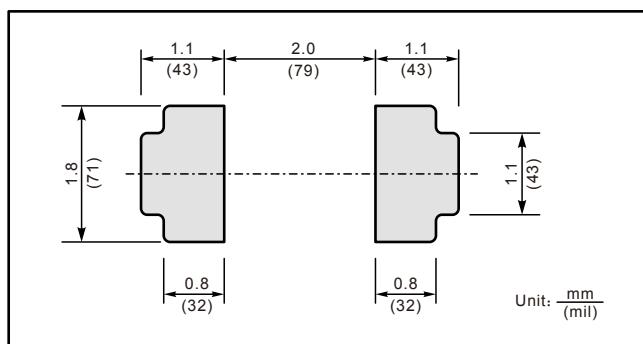
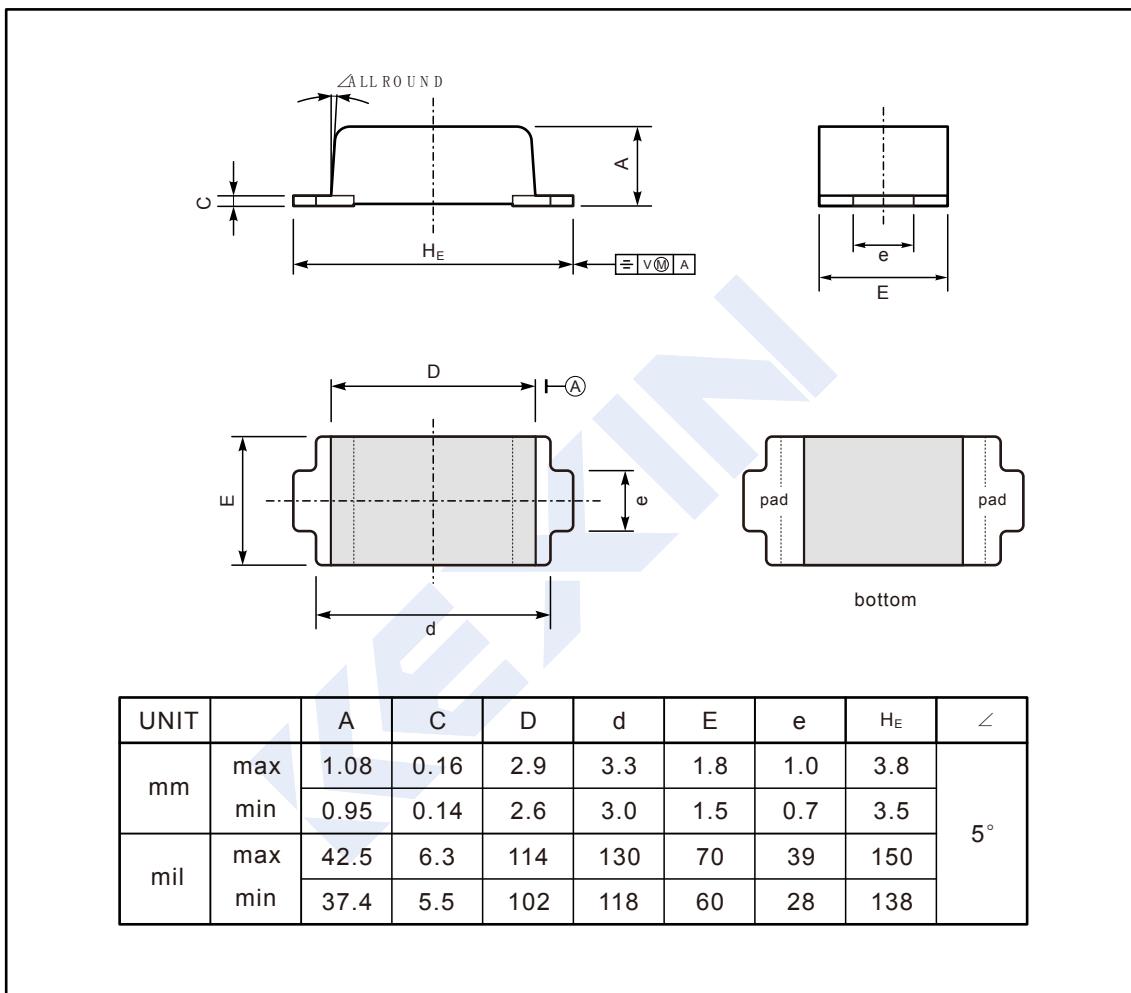


Rectifier Diodes

S1AFH~S1MFH

■ Typical Application

Plastic surface mounted package; 2 leads

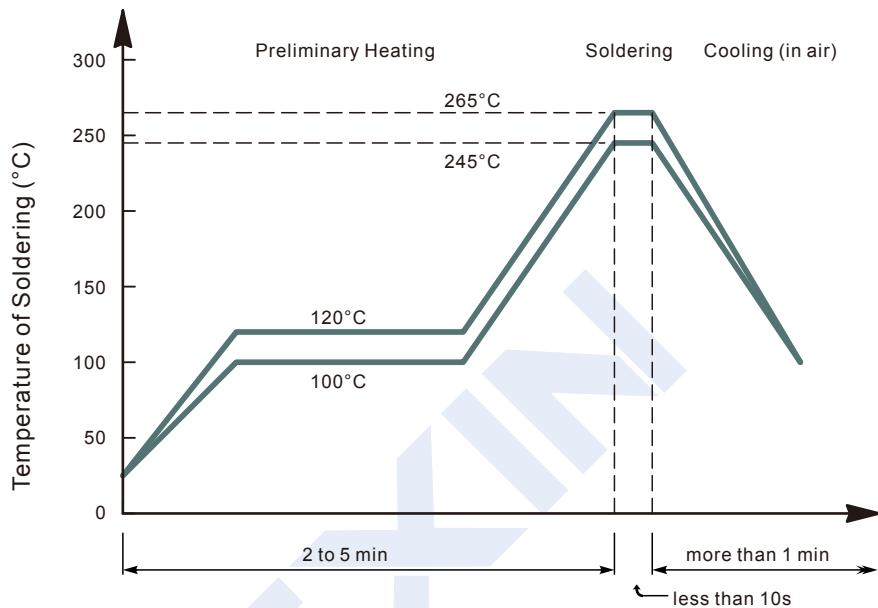


Rectifier Diodes

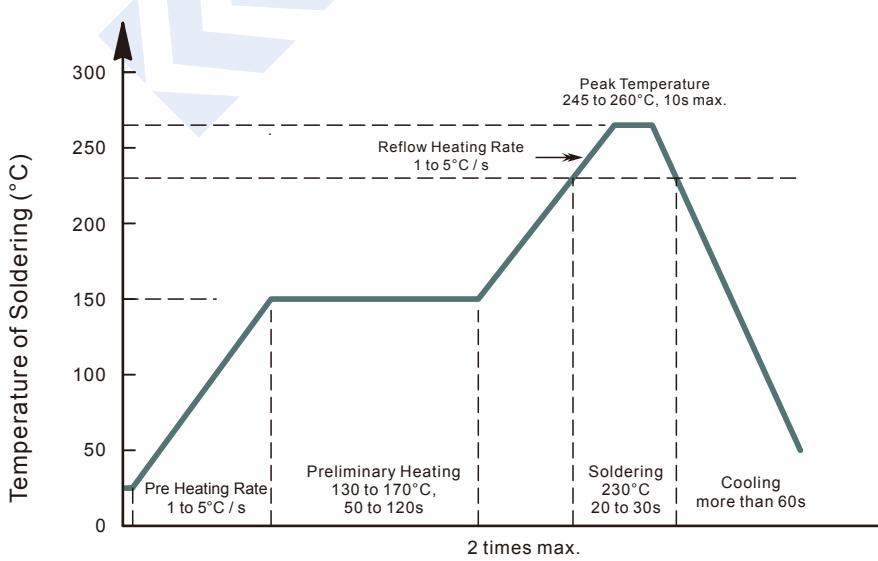
S1AFH~S1MFH

■ Typical Application

Recommended condition of flow soldering



Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters; time length of peak temperature (longer), time length of soldering (longer), thickness of solder paste (thicker)